

DATA SHEET

NEC

GaAs HBT INTEGRATED CIRCUIT μ PG2315T5T

2.4 GHz SINGLE BAND POWER AMPLIFIER FOR W-LAN

DESCRIPTION

The μ PG2315T5T is GaAs HBT MMIC power amplifier which were developed for W-LAN.

This device realizes high efficiency, high gain and high output power by using InGaP HBT. This device is housed in a 16-pin plastic QFN (Quad Flat Non-leaded) package. And this package is able to high-density surface mounting.

FEATURES

- Operation frequency : $f_{opt} = 2\ 400$ to $2\ 500$ MHz (2 450 MHz TYP.)
- Supply voltage : $V_{CC1, 2} = 3.0$ to 3.6 V (3.3 V TYP.)
- Control voltage : $V_{enable} = 0$ to 2.95 V (2.85 V TYP.)
- Circuit current : $I_{CC} = 130$ mA TYP. @ $V_{CC1, 2} = 3.3$ V, $V_{enable} = 2.85$ V,
 $P_{out} = +18$ dBm (at OFDM modulation)
- Power gain : $G_P = 26$ dB TYP. @ $V_{CC1, 2} = 3.3$ V, $V_{enable} = 2.85$ V,
 $P_{out} = +18$ dBm (at OFDM modulation)
- Gain flatness : $\Delta G_P = 1.0$ dB TYP. @ $f = 2.4$ to 2.5 GHz, $V_{CC1, 2} = 3.3$ V, $V_{enable} = 2.85$ V,
 $P_{out} = +18$ dBm (at OFDM modulation)
- Error vector magnitude : $EVM = 3\%$ TYP. @ $V_{CC1, 2} = 3.3$ V, $V_{enable} = 2.85$ V,
 $P_{out} = +18$ dBm (at OFDM modulation)
- Harmonics : $2f_0, 3f_0, 4f_0 = 30$ dBc TYP. @ $V_{CC1, 2} = 3.3$ V, $V_{enable} = 2.85$ V,
 $P_{out} = +18$ dBm (at OFDM modulation)
- High-density surface mounting : 16-pin plastic QFN package ($3.0 \times 3.0 \times 0.75$ mm)

APPLICATIONS

- Power Amplifier for W-LAN (802.11 b/g) and DECT

ORDERING INFORMATION

Part Number	Order Number	Package	Marking	Supplying Form
μ PG2315T5T-E2	μ PG2315T5T-E2-A	16-pin plastic QFN (Pb-Free)	2315	<ul style="list-style-type: none">• Embossed tape 8 mm wide• Pin 1, 12 face the perforation side of the tape• Qty 3 kpcs/reel

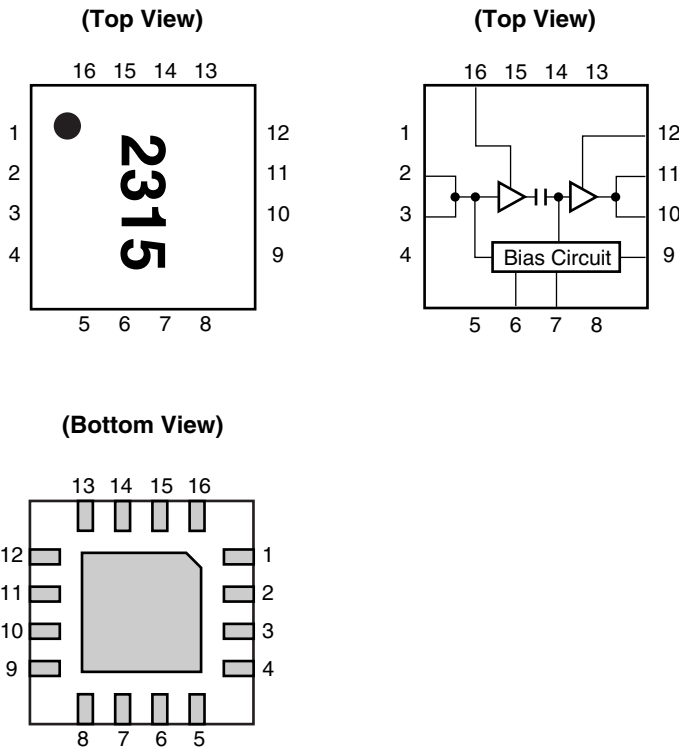
Remark To order evaluation samples, contact your nearby sales office.

Part number for sample order: μ PG2315T5T

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

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Not all products and/or types are available in every country. Please check with an NEC Electronics sales representative for availability and additional information.

PIN CONNECTIONS AND INTERNAL BLOCK DIAGRAM



Pin No.	Pin Name
1	N.C.
2	INPUT
3	INPUT
4	N.C.
5	N.C.
6	V _{enable1}
7	V _{enable2}
8	N.C.
9	V _{det}
10	OUTPUT
11	OUTPUT
12	V _{cc2}
13	N.C.
14	N.C.
15	N.C.
16	V _{cc1}

ABSOLUTE MAXIMUM RATINGS (T_A = +25°C, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Supply Voltage	V _{cc1, 2}	5.0	V
Control Voltage	V _{enable}	4.0	V
Input Power	P _{in}	+10	dBm
Power Dissipation	P _D	500 ^{Note}	mW
Operating Ambient Temperature	T _A	-45 to +85	°C
Storage Temperature	T _{stg}	-55 to +150	°C

Note Mounted on double-sided copper-clad 50 × 50 × 1.6 mm epoxy glass PWB, T_A = +85°C

RECOMMENDED OPERATING RANGE (T_A = +25°C, unless otherwise specified)

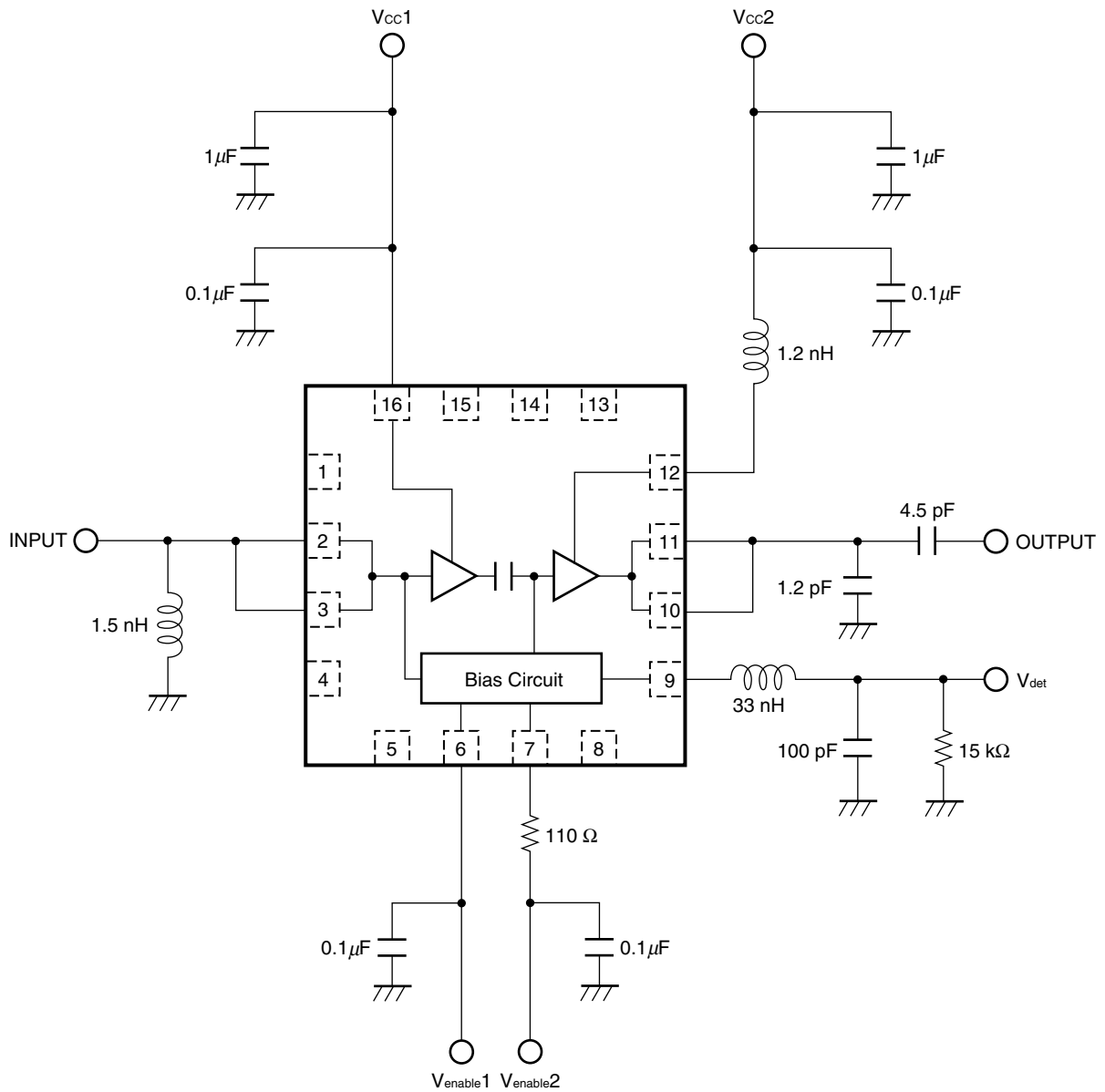
Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Operating Frequency	f _{opt}	2 400	2 450	2 500	MHz
Supply Voltage	V _{cc1, 2}	3.0	3.3	3.6	V
Control Voltage	V _{enable}	0	2.85	2.95	V

ELECTRICAL CHARACTERISTICS

(T_A = +25°C, V_{cc1, 2} = 3.3 V, V_{enable} = 2.85 V, f = 2 400 to 2 500 MHz, External input and output matching, unless otherwise specified)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Circuit Current	I _{cc}	P _{out} = +18 dBm (at OFDM modulation)	–	130	150	mA
Power Gain	G _P	P _{out} = +18 dBm (at OFDM modulation)	23	26	–	dB
Gain Flatness	ΔG _P	P _{out} = +18 dBm (at OFDM modulation)	–	1.0	1.5	dB
Error Vector Magnitude	EVM	P _{out} = +18 dBm (at OFDM modulation)	–	3.0	–	%
Input Return Loss	RL _{in}	P _{in} = –30 dBm	–	15	–	dB
Output Return Loss	RL _{out}	P _{in} = –30 dBm	–	10	–	dB
2nd Harmonics	2f _o	P _{out} = +18 dBm (at OFDM modulation)	–	30	–	dBc
3rd Harmonics	3f _o	P _{out} = +18 dBm (at OFDM modulation)	–	30	–	dBc
4th Harmonics	4f _o	P _{out} = +18 dBm (at OFDM modulation)	–	30	–	dBc
Power Detector Voltage	V _{det}		0.5	–	2.0	V

EVALUATION CIRCUIT



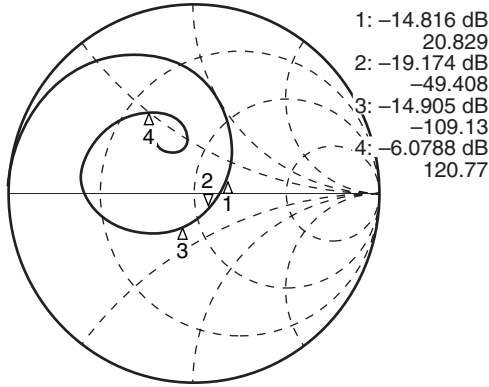
The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

TYPICAL CHARACTERISTICS

S-parameter (Reference Data) –This data is included external matching components–

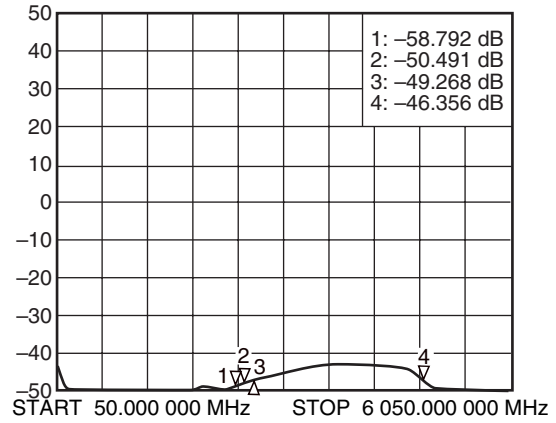
Condition : Vcc1 = Vcc2 = 3.3 V, Venable1 = Venable2 = 2.85 V, Iq = 58 mA

S11-FREQUENCY

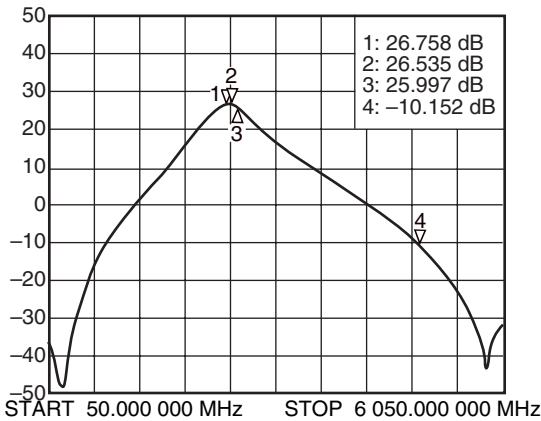


START 50.000 000 MHz STOP 6 050.000 000 MHz

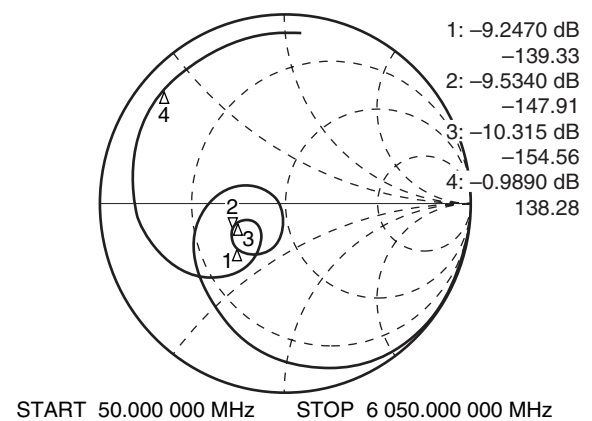
S12-FREQUENCY



S21-FREQUENCY



S22-FREQUENCY

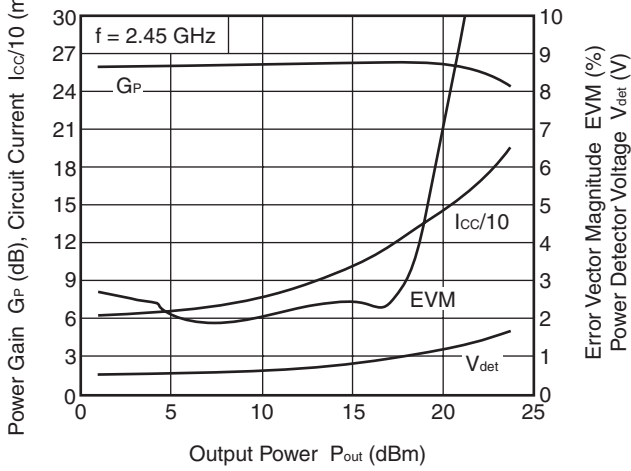


Remarks 1. The graphs indicate nominal characteristics.

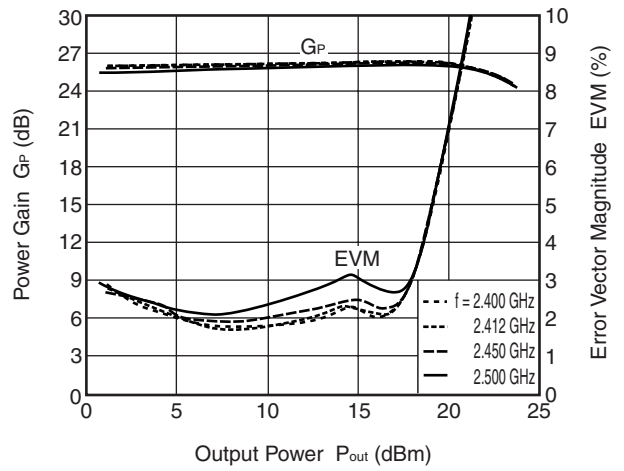
- 2. Marker1 : 2.40 GHz
- Marker2 : 2.45 GHz
- Marker3 : 2.50 GHz
- Marker4 : 4.90 GHz

Typical power performance characteristics ($V_{cc1} = V_{cc2} = 3.3\text{ V}$, $V_{enable1} = V_{enable2} = 2.85\text{ V}$)

G_P , $I_{cc/10}$, EVM, V_{det} vs. OUTPUT POWER



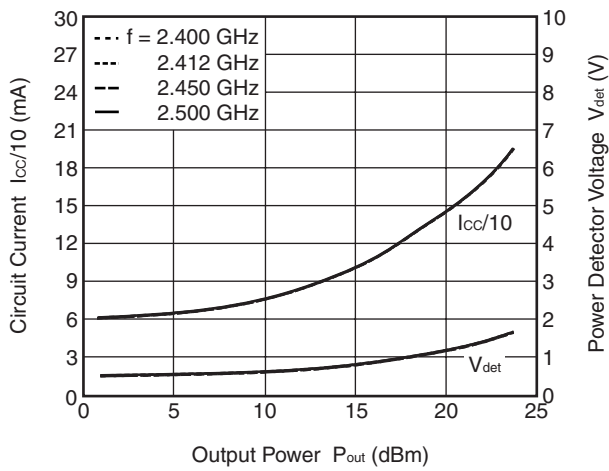
G_P , EVM vs. OUTPUT POWER



Remark The graphs indicate nominal characteristics.

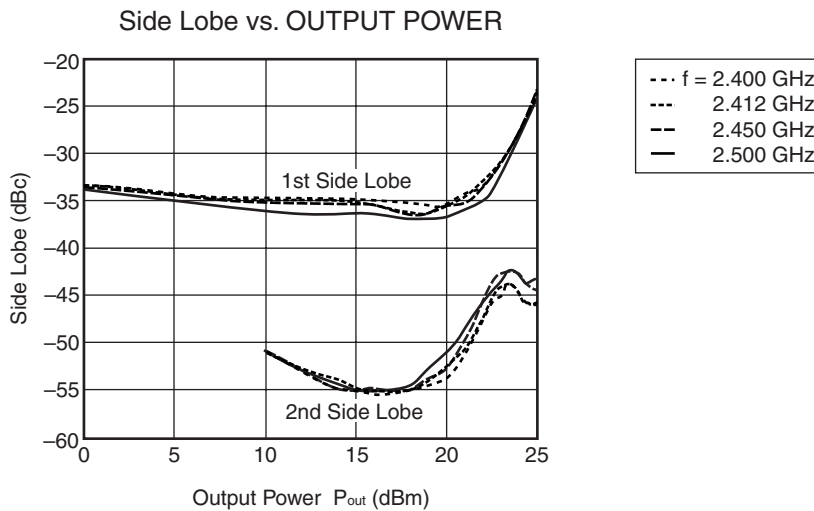
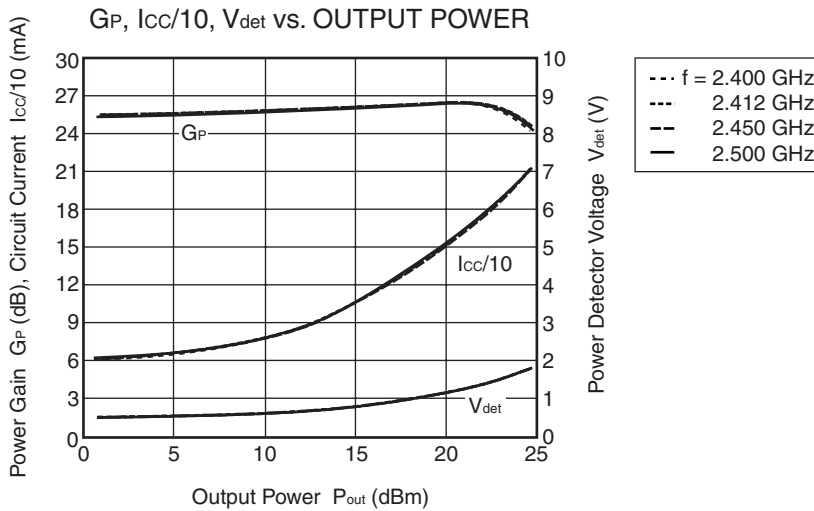
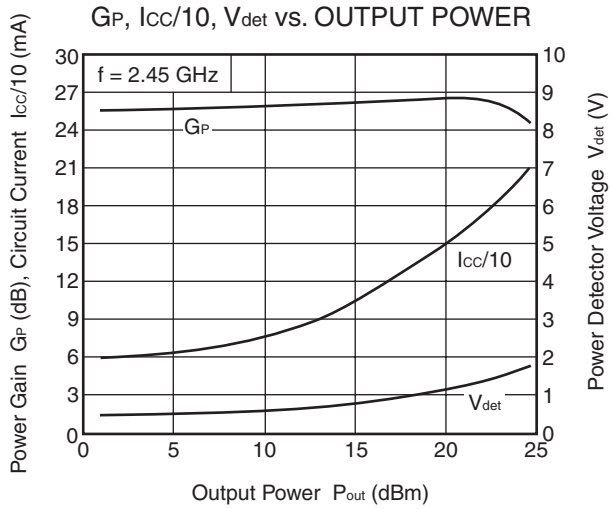
Typical V_{det} performance characteristics ($V_{cc1} = V_{cc2} = 3.3\text{ V}$, $V_{enable1} = V_{enable2} = 2.85\text{ V}$)

$I_{cc/10}$, V_{det} vs. OUTPUT POWER



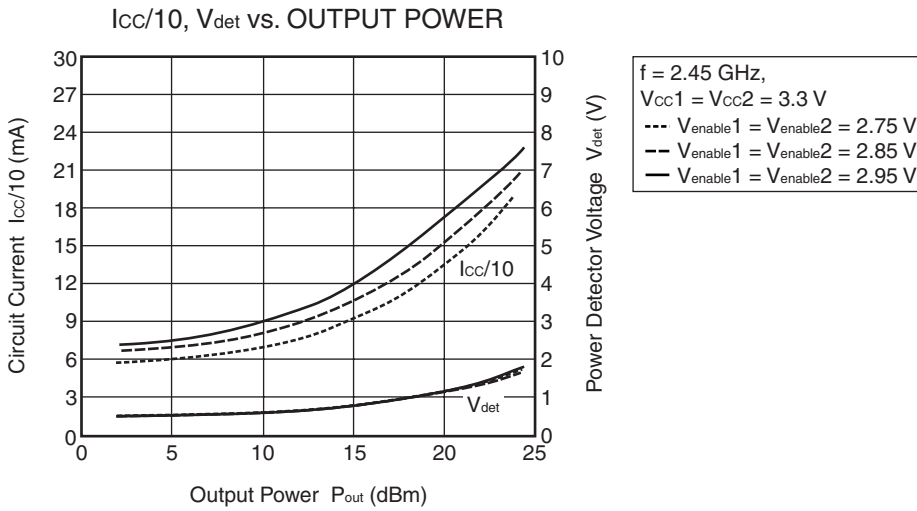
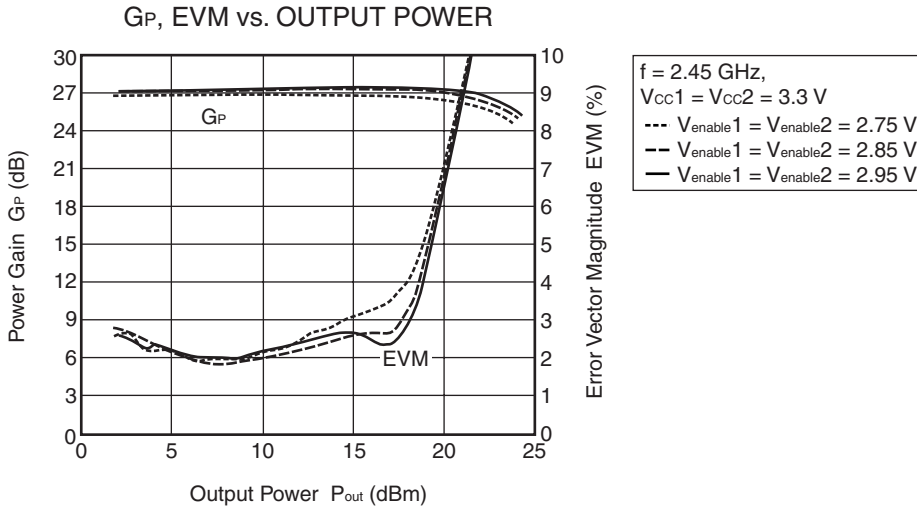
Remark The graph indicates nominal characteristics.

Typical 802.11b power performance characteristics ($V_{cc1} = V_{cc2} = 3.3\text{ V}$, $V_{enable1} = V_{enable2} = 2.85\text{ V}$)



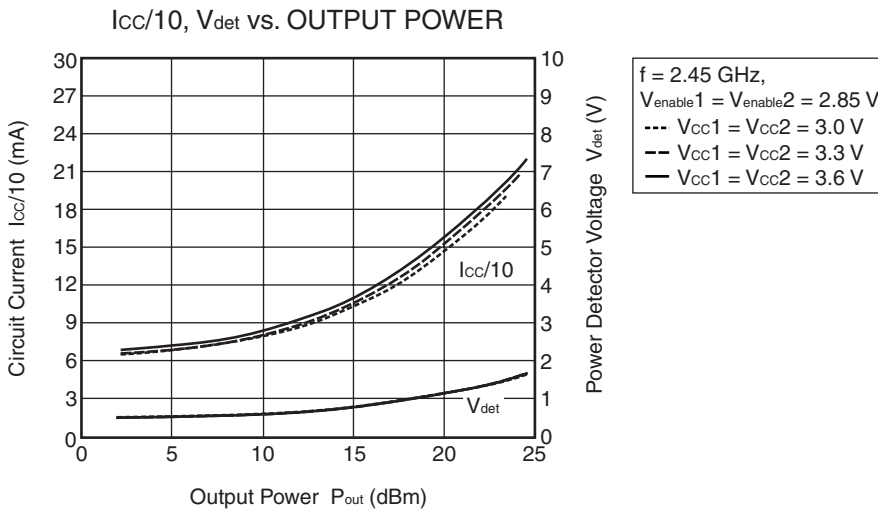
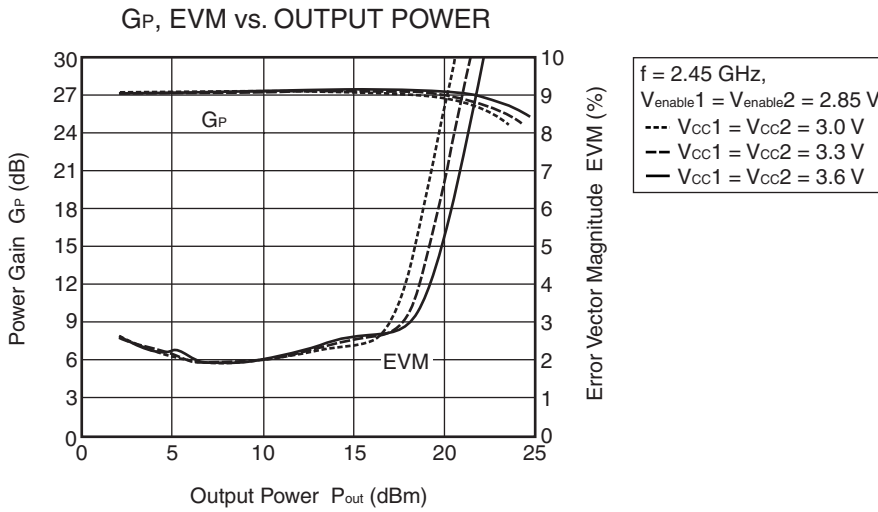
Remark The graphs indicate nominal characteristics.

Typical V_{enable} dependency of power performance characteristics



Remark The graphs indicate nominal characteristics.

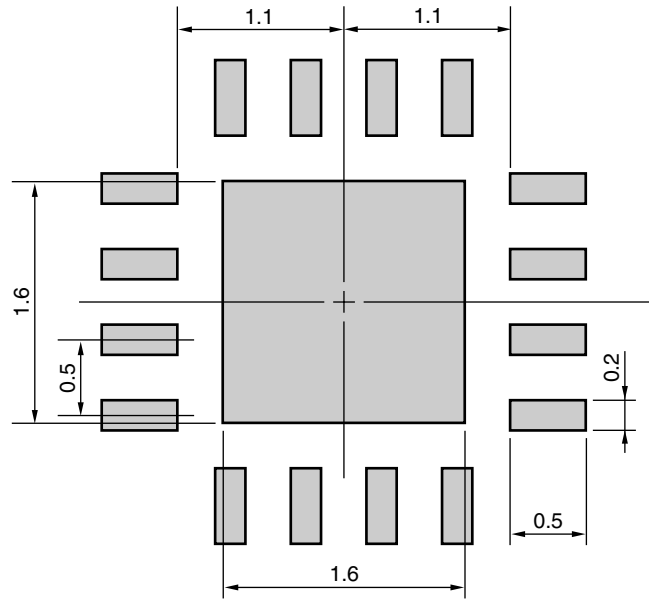
Typical Vcc dependency of power performance characteristics



Remark The graphs indicate nominal characteristics.

MOUNTING PAD DIMENSIONS

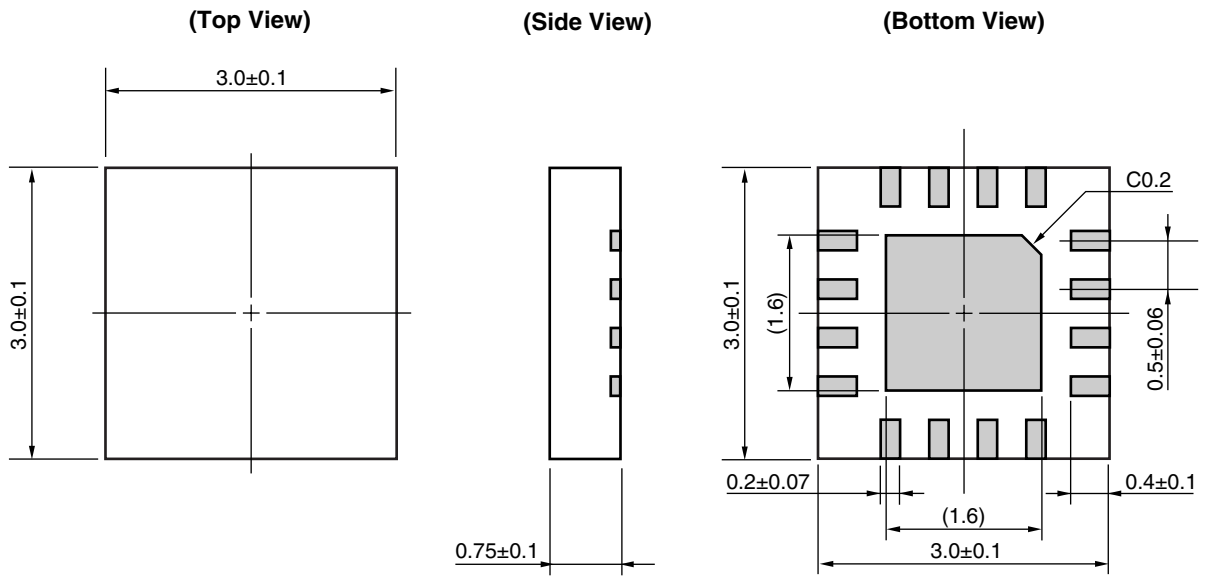
16-PIN PLASTIC QFN (UNIT: mm)



Remark The mounting pad layouts in this document are for reference only.

PACKAGE DIMENSIONS

16-PIN PLASTIC QFN (UNIT: mm)



Remark () : Reference value

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions	Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature) : 260°C or below Time at peak temperature : 10 seconds or less Time at temperature of 220°C or higher : 60 seconds or less Preheating time at 120 to 180°C : 120±30 seconds Maximum number of reflow processes : 3 times Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	IR260
Wave Soldering	Peak temperature (molten solder temperature) : 260°C or below Time at peak temperature : 10 seconds or less Preheating temperature (package surface temperature) : 120°C or below Maximum number of flow processes : 1 time Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	WS260
Partial Heating	Peak temperature (terminal temperature) : 350°C or below Soldering time (per side of device) : 3 seconds or less Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	HS350

Caution Do not use different soldering methods together (except for partial heating).

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<p>Caution</p>	<p>GaAs Products</p>	<p>This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.</p> <ul style="list-style-type: none"> • Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below. <ol style="list-style-type: none"> 1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials. 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal. • Do not burn, destroy, cut, crush, or chemically dissolve the product. • Do not lick the product or in any way allow it to enter the mouth.
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► For further information, please contact

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